NSN 5961-01-064-6885

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-064-6885 **Inclosure Material:** Glass **Overall Length:** 0.170 inches **Overall Diameter:** 0.076 inches **End Application:** Dgeneral purpose electronic test equipment gpete; olive perry class ffg; yellowstone class ad-41; support equipment, f-15 aircraft; strategic weapon systems (poseidon and trident); emory s. Land as **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 12.0 reverse voltage, peak **Current Rating Per Characteristic:** 10.00 milliamperes forward current, average **Special Features:** Weapon system essential **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: